NSN 5962-00-513-3355



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-00-513-3355 **Body Length:** 0.380 inches **Body Width:** 0.195 inches **Body Height:** 0.075 inches **Maximum Power Dissipation Rating:** 150.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** Dual 4 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Memory Device Type:** Rom **Special Features:** Burn-in test 168 hr **Test Data Document:** 03640-6088749 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 14 flat leads Shelf Life: N/a **Unit Of Measure:**

Fiig: A458a0

Demilitarization: Yes - demil/mli